National Semiconductor

DS1630/DS3630 Hex CMOS Compatible Buffer

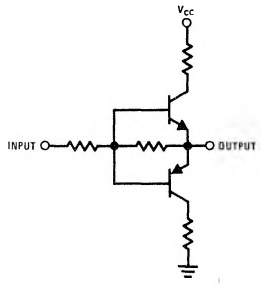
General Description

The DS1630/DS3630 is a high current buffer intended for use with CMOS circuits interfacing with peripherals requiring high drive currents. The DS1630/DS3630 features low quiescent power consumption (typically 50 μW) as well as high-speed driving of capacitive loads such as large MOS memories. The design of the DS1630/DS3630 is such that V_{CC} current spikes commonly found in standard CMOS circuits cannot occur, thereby, reducing the total transient and average power when operating at high frequencies.

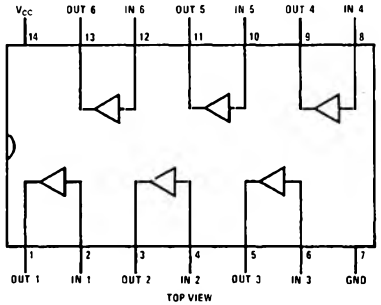
Features

- High-speed capacitive driver
- Wide supply voltage range
- Input/output CMOS compatibility
- No internal transient V_{CC} current spikes
- 50 μW standby power (typ.)
- Fan out of 10 standard TTL loads

Equivalent Schematic and Connection Diagrams

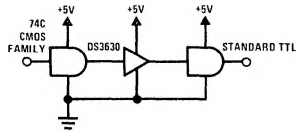


Dual-In-Line Package

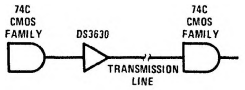


Order Number DS1630J, DS3630J or DS3630N

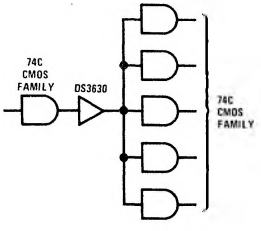
Typical Applications



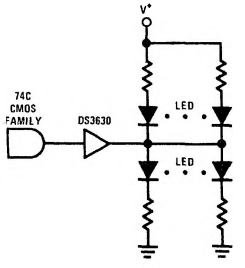
CMOS to TTL Interface



CMOS To Transmission Line Interface



CMOS To CMOS Interface



LED Driver

Absolute Maximum Ratings (Note 1)

Supply Voltage	16V
Input Voltage	16V
Output Voltage	16V
Lead Temperature (Soldering, 10 seconds)	300°C

Operating Conditions

	MIN	MAX	UNITS
Supply Voltage (V_{CC})	3	15	V
Temperature (T_A)			
DS1630	−55	+125	°C
DS3630	0	+70	°C

DC Electrical Characteristics (Notes 2 and 3)

PARAMETER	CONDITIONS		MIN	TYP	MAX	UNITS
I_{INH} Logical "1" Input Current	$V_{IN} = V_{CC}$, $I_{OUT} = -400\mu A$	DS1630		90	200	μA
		DS3630		90	200	μA
	$V_{IN} = V_{CC} - 2.0V$, $I_{OUT} = 16$ mA	DS1630		0.5	3.2	mA
		DS3630		0.5	1.5	mA
I_{INL} Logical "0" Input Current	$V_{IN} = 0.4V$, $I_{OUT} = 16$ mA	DS1630		−0.15	−1	mA
		DS3630		$V_{CC}-150$	−800	μA
V_{OH} Logical "1" Output Voltage	$V_{IN} = V_{CC}$, $I_{OUT} = -400\mu A$	DS1630	$V_{CC}-1$	$V_{CC}-0.75$		V
		DS3630	$V_{CC}-0.9$	$V_{CC}-0.75$		V
	$V_{IN} = V_{CC} - 0.4V$, $I_{OUT} = 16$ mA	DS1630	$V_{CC}-2.5$	$V_{CC}-2.0$		V
		DS3630	$V_{CC}-2.5$	$V_{CC}-2.0$		V
V_{OL} Logical "0" Output Voltage	$V_{IN} = 0V$, $I_{OUT} = 400\mu A$	DS1630		0.75	1	V
		DS3630		0.75	0.9	V
	$V_{IN} = 0V$, $I_{OUT} = 16$ mA	DS1630		0.95	1.3	V
		DS3630		0.95	1.3	V
	$V_{IN} = 0.4V$, $I_{OUT} = 16$ mA	DS1630		1.2	1.6	V
		DS3630		1.2	1.5	V

AC Electrical Characteristics $V_{CC} = 5.0V$, $T_A = 25°C$ unless otherwise specified.

PARAMETER	CONDITIONS	MIN	TYP	MAX	UNITS
t_{pd0} Propagation Delay to a Logical "0"	$C_L = 50$ pF		30	45	ns
	$C_L = 250$ pF		40	60	ns
	$C_L = 500$ pF		50	75	ns
t_{pd1} Propagation Delay to a Logical "1"	$C_L = 50$ pF		15	25	ns
	$C_L = 250$ pF		35	50	ns
	$C_L = 500$ pF		50	75	ns

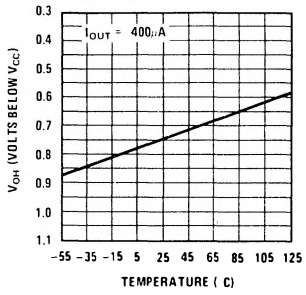
Note 1: "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. Except for "Operating Temperature Range" they are not meant to imply that the devices should be operated at these limits. The table of "Electrical Characteristics" provides conditions for actual device operation.

Note 2: Unless otherwise specified min/max limits apply across the −55°C to +125°C temperature range for the DS1630 and across the 0°C to +70°C range for the DS3630. All typicals are given for $V_{CC} = 5.0V$ and $T_A = 25°C$.

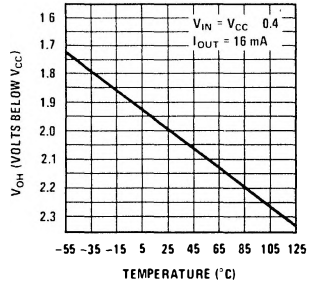
Note 3: All currents into device pins shown as positive, out of device pins as negative, all voltages referenced to ground unless otherwise noted. All values shown as max or min on absolute value basis.

Typical Performance Characteristics

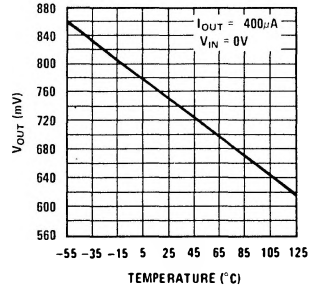
V_{OH} vs Temperature, $V_{IN} = V_{CC}$



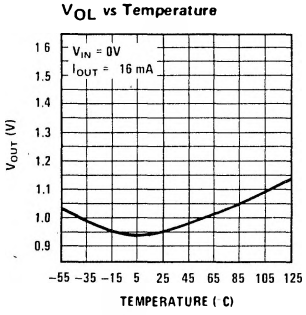
V_{OH} Active vs Temperature



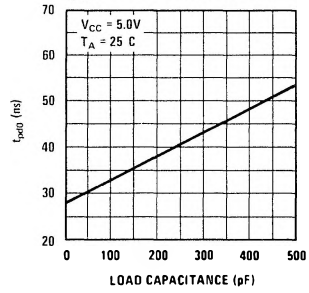
V_{OL} vs Temperature



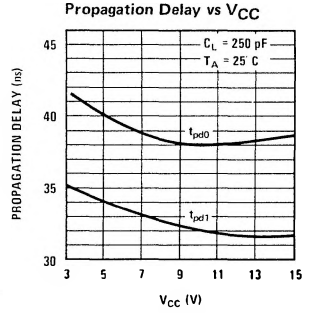
V_{OL} vs Temperature



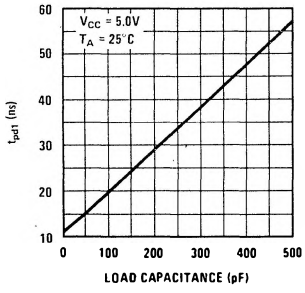
t_{pdo} vs Load Capacitance



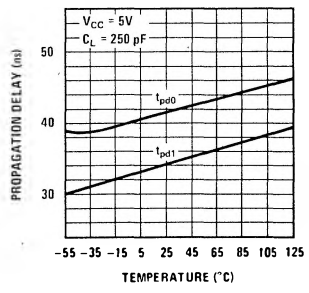
Propagation Delay vs V_{CC}



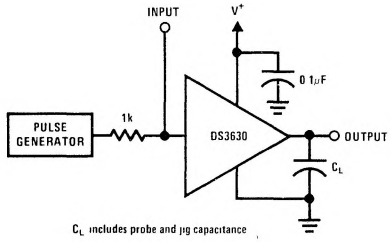
t_{pd1} vs Load Capacitance



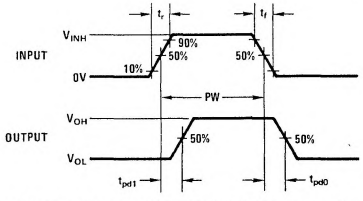
Propagation Delay vs Temperature



AC Test Circuit and Switching Time Waveforms



C_L includes probe and jig capacitance



Pulse Generator characteristics: PRR = 1.0 MHz, PW = 500 ns, $t_r = t_f < 10$ ns, V_{IN} = 0 to V_{CC}